

FMW79N60S1HF

FUJI POWER MOSFET

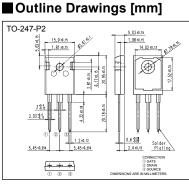
Super J-MOS series

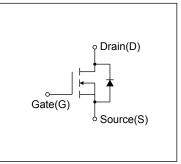
N-Channel enhancement mode power MOSFET

Features	
Low on-state resistance	
Low switching loss	
easy to use (more controllabe switchin	g dV/dt by R _g)

Applications

UPS Server Telecom Power conditioner system Power supply





Equivalent circuit schematic

Absolute Maximum Ratings at Tc=25°C (unless otherwise specified)

Description	Symbol	Characteristics	Unit	Remarks
Drain Source Voltage	VDS	600	V	
Drain-Source Voltage	VDSX	600	V	V _{GS} =-30V
Continuous Drain Current		±68	А	Tc=25°C Note*1
Continuous Drain Current	ID	±43	А	Tc=100°C Note*1
Pulsed Drain Current	IDP	±204	А	
Gate-Source Voltage	V _{GS}	±30	V	
Repetitive and Non-Repetitive Maximum Avalanche Current	lar	13.5	А	Note *2
Non-Repetitive Maximum Avalanche Energy	EAS	3194.4	mJ	Note *3
Maximum Drain-Source dV/dt	dV _{DS} /dt	50	kV/µs	V _{DS} ≤ 600V
Peak Diode Recovery dV/dt	dV/dt	15	kV/µs	Note *4
Peak Diode Recovery -di/dt	-di/dt	50	A/µs	Note *5
Mawimum Dawan Diabinatian	PD	2.5	W	T₄=25°C
Maximum Power Dissipation		545	vv	Tc=25°C
On susting and Otenson Temperature reason	Tch	150	°C	
Operating and Storage Temperature range	T _{stg}	-55 to +150	°C	

Note *1 : Limited by maximum channel temperature. Note *2 : Teh≤150°C, See Fig.1 and Fig.2 Note *3 : Starting Teh=25°C, IAs=8.1A, L=89.3mH, VpD=60V, Rg=50Ω, See Fig.1 and Fig.2 EAS limited by maximum channel temperature and avalanche current.

Note *4 : $I_F \le -20A$, $-di/dt = 50A/\mu s$, $V_{DD} \le 300V$, $T_{ch} \le 150^{\circ}C$. Note *5 : $I_F \le -20A$, $dV/dt = 15kV/\mu s$, $V_{DD} \le 300V$, $T_{ch} \le 150^{\circ}C$.

■ Electrical Characteristics at T_c=25°C (unless otherwise specified) Static Ratings

Description	Symbol	Conditions		min.	typ.	max.	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250μA V _{GS} =0V		600	-	-	V
Gate Threshold Voltage	V _{GS(th)}	I₀=250µA V₀s=V₀s		2.5	3.0	3.5	V
Zero Gate Voltage Drain Current	loss	V _{DS} =600V V _{GS} =0V	T _{ch} =25°C	-	-	25	- μΑ
		V _{DS} =480V V _{GS} =0V	T _{ch} =125°C	-	-	250	
Gate-Source Leakage Current	lass	V _{GS} = ±30V V _{DS} =0V		-	10	100	nA
Drain-Source On-State Resistance	R _{DS(on)}	I _D =34A V _{GS} =10V		-	0.034	0.04	Ω
Gate resistance	RG	f=1MHz, open drain		-	1.3	-	Ω

Dynamic Ratings

Description	Symbol	Conditions	min.	typ.	max.	Unit
Forward Transconductance	g fs	I _D =34A V _{DS} =25V	27.5	55	-	s
Input Capacitance	Ciss	V _{DS} =10V	-	7000	-	
Output Capacitance	Coss	V _{GS} =0V	-	14500	-	
Reverse Transfer Capacitance	Crss	f=1MHz	-	1300	-	
Effective output capacitance, energy related (Note *6)	C _{o(er)}	V _{GS} =0V V _{DS} =0480V	-	350	-	pF
Effective output capacitance, time related (Note *7)	C _{o(tr)}	V _{GS} =0V V _{DS} =0480V ID=constant	-	1330	-	
Turne Ore Times	t _{d(on)}		-	40	-	
Turn-On Time	tr	V _{DD} =400V, V _{GS} =10V	-	107	-	ns
Turn Off Time	t _{d(off)}	│ I₅=34A, R₅=6.2Ω _ See Fig.3 and Fig.4	-	199	-	
Turn-Off Time	tr		-	20	-	
Total Gate Charge	QG	V _{DD} =480V, I _D =68A V _{GS} =10V See Fig.5	-	203	-	nC
Gate-Source Charge	Q _{GS}		-	44	-	
Gate-Drain Charge	QGD		-	76	-	
Drain-Source crossover Charge	Qsw		-	27	-	1

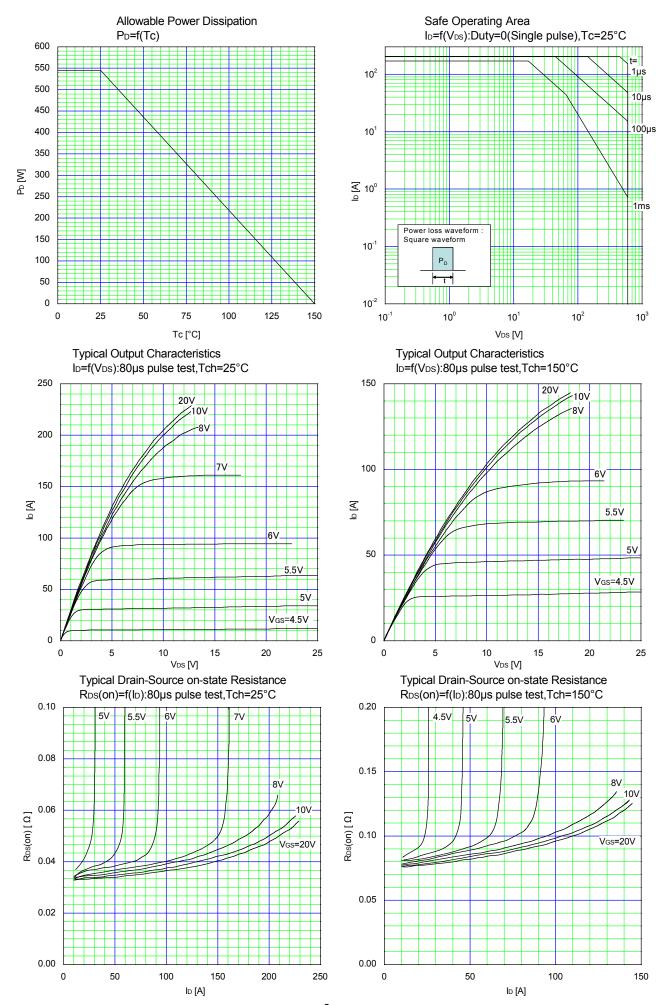
Note *6 : $C_{o(er)}$ is a fixed capacitance that gives the same stored energy as C_{oss} while V_{Ds} is rising from 0 to 80% BV_{DSS}. Note *7 : $C_{o(tr)}$ is a fixed capacitance that gives the same charging times as C_{oss} while V_{Ds} is rising from 0 to 80% BV_{DSS}.

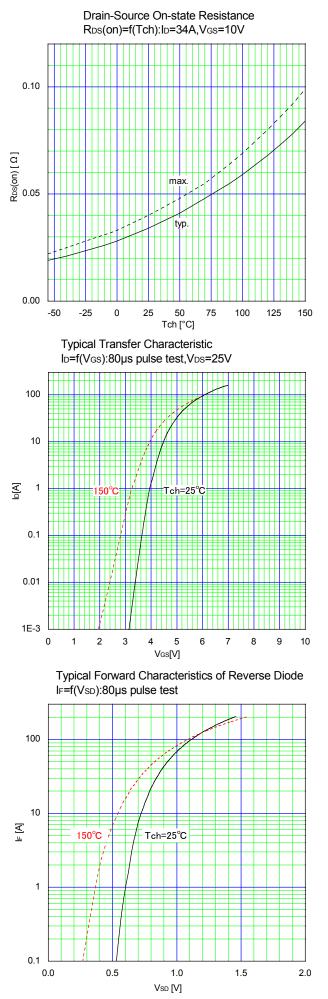
Reverse Diode

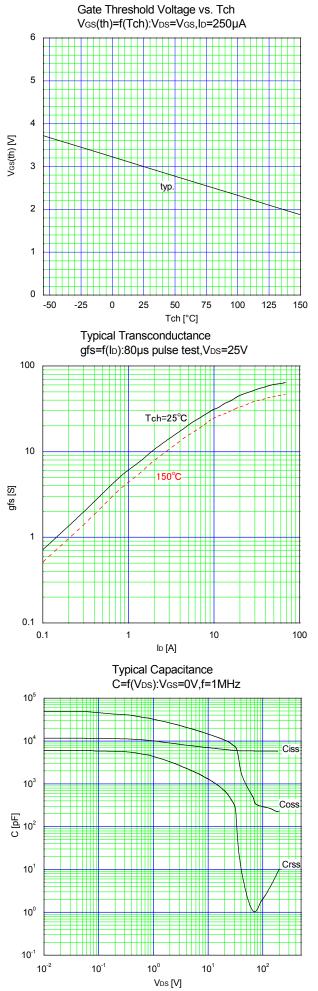
Description	Symbol	Conditions	min.	typ.	max.	Unit
Avalanche Capability	lav	L=19.3mH, T _{et} =25°C See Fig.1 and Fig.2	13.5	-	-	А
Diode Forward On-Voltage	Vsd	IF=68A, VGS=0V Tch=25°C	-	1.0	1.35	V
Reverse Recovery Time	trr	IF=20A, VGS=0V	-	600	-	ns
Reverse Recovery Charge	Qrr	V ₂₀ =300V −di/dt=50A/µs T _{ch} =25°C See Fig.6	-	8.7	-	μC
Peak Reverse Recovery Current	Ігр		-	29	-	А

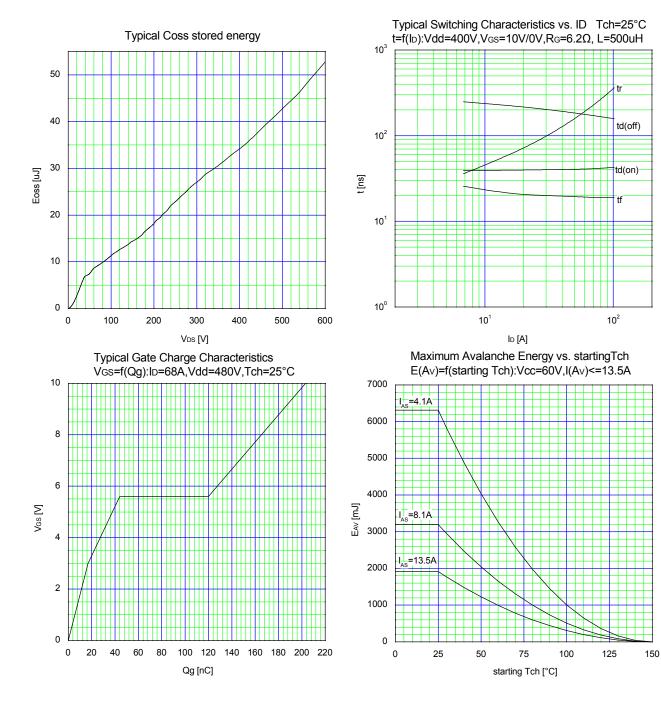
Thermal Characteristics

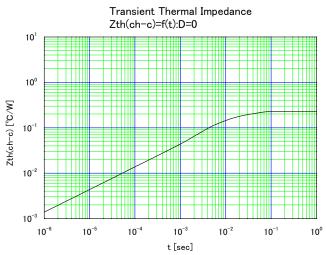
Description	Symbol	min.	typ.	max.	Unit
Channel to Case	R _{th(ch-c)}	-	-	0.23	°C/W
Channel to Ambient	R _{th(ch-a)}	-	-	50	°C/W











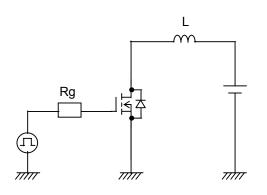
VGS

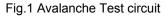
VDS

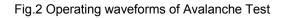
DI

BVDSS

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IAV

+10V

-15\

0

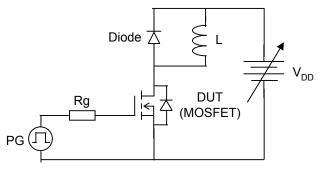


Fig.3 Switching Test circuit

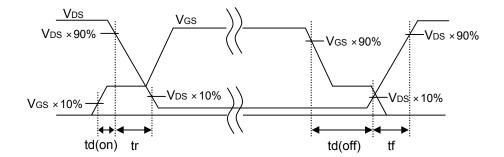


Fig.4 Operating waveform of Switching Test

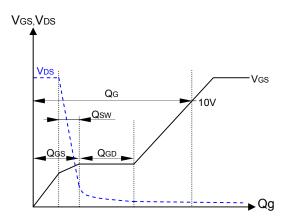
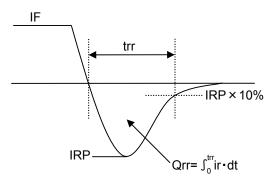
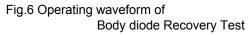


Fig.5 Operating waveform of Gate charge Test

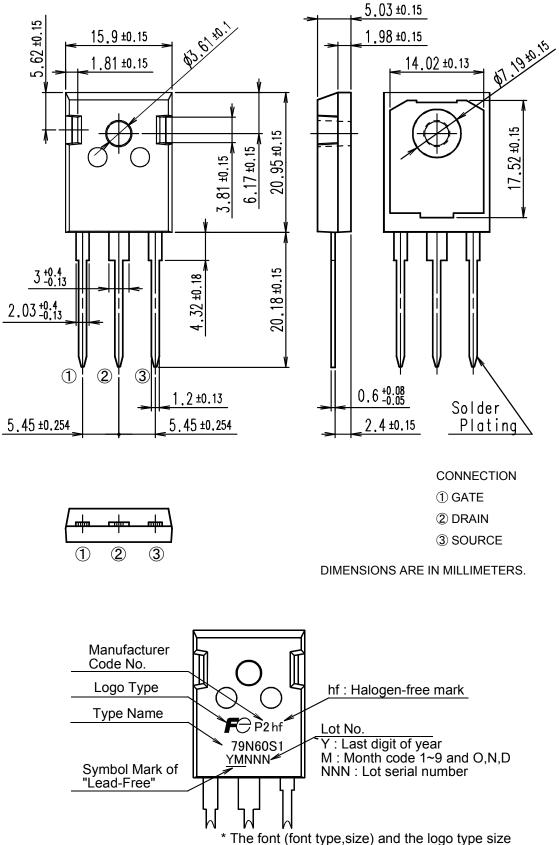




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Outview: TO-247-P2 Package



The font (font type,size) and the logo type siz might be actually different.

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